

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1 (original). A process for designing semi-conductor memory components (1), in particular DRAM components, whereby the process comprises the following steps:

- designing of a first layout (2') for a module (2) of the semi-conductor memory component (1) to be used for a first configuration of the semi-conductor memory component (1);
- designing of a second layout (2'') for the semi-conductor memory module (2) to be used for a second configuration of the semi-conductor memory component (1);
- using of the first layout (2') or of the second layout (2'') for the total layout of the semi-conductor memory component (1), depending on the particular configuration of the semi-conductor memory component (1).

2 (original). A process according to Claim 1, in which the process comprises the following additional steps:

- designing of a third layout (2''') for the semi-conductor memory component module (2) to be used for a third configuration of the semi-conductor memory component (1);
- using of the first, second or third layout (2', 2'', 2''') for the total layout of the semi-conductor memory components (1), depending on the particular configuration of the semi-conductor memory component (1).

3 (currently amended). A process according to ~~Claims 1 or~~ Claim 2, in which the first and second, in particular the first, second and third layouts (2', 2'', 2''') for the semi-conductor memory component module (2) all have essentially the same exterior dimensions.

4 (currently amended). A process according to ~~one of above claims~~ Claim 2, in which the first and second, in particular the first, second and third layouts (2', 2'', 2''') for the semi-conductor memory component module (2) are all essentially arranged at the same locality of the total layout.

5 (currently amended). A process according to ~~one of the above claims~~ Claim 1, in which the process additionally comprises the following steps:

- designing of a further layout (3) for a further module (3a) of the semi-conductor memory component (1);
- using of the further layout (3) for the total layout of the semi-conductor memory component (1), not dependent on the particular configuration of the semi-conductor memory component (1).

6 (currently amended). A process according to ~~one of the above claims~~ Claim 1, in which the semi-conductor memory component (1) is a RAM component.

7 (original). A process according to Claim 6, in which the semi-conductor memory component (1) is a DRAM component.

8 (original). A process according to Claim 7, in which the structure of the DRAM component (1) is essentially identical, as with DRAM components configurable by means of fuses or bonds.

9 (currently amended). A process according to ~~one of the above claims~~ Claim 7, in which the first and second, in particular the first, second and third layouts (2', 2'', 2'''), and/or the further layout (3) and/or additional layouts (9', 9'', 9'''; 4', 4'', 4''') - in particular when used jointly - are exclusively suited to be used in semi-conductor memory components (1), in particular RAM or DRAM components.

10 (currently amended). A process according to ~~one of the above claims~~ Claim 1, in which the module (2) is allocated to a relatively high and/or medium semi-conductor component design abstraction level, in particular to a sub-system, algorithm, register transfer, logic and/or module level.

11 (original). A process according to Claim 10, in which the module (2) is not allocated to the highest semi-conductor component design abstraction level, in particular not to the system and/or CPU/memory level.

12 (currently amended). A process according to ~~one of the previous claims~~ Claim 1, which produces a total layout for an SDR or DDR-DRAM and/or a DDR2-DRAM component, corresponding with the particular semi-conductor memory component configuration selected in each case.

13 (currently amended). A process according to ~~one of the above claims~~ Claim 1, which produces corresponding with the particular semi-conductor memory component configuration selected in each case a total layout for a semi-conductor memory component (1) with a number of data output bits corresponding with the particular configuration.

14 (currently amended). A process according to ~~one of the above claims~~ Claim 1, which produces corresponding with the particular semi-conductor memory component configuration selected in each case a total layout for a semi-conductor memory component (1) with a data and/or clock pulse rate corresponding with the particular configuration.

15 (currently amended). A process according to ~~one of the above claims~~ Claim 1, which produces corresponding with the particular semi-conductor memory component configuration selected in each case a total layout for a semi-conductor memory component (1) with a voltage supply designed in accordance with the particular configuration.

16 (original). A process for manufacturing semi-conductor memory components (1), in particular DRAM components, whereby the process comprises the following steps:

- designing of a first layout (2') for a module (2) of the semi-conductor memory component (1) to be used in a first configuration of the semi-conductor memory component (1);
- designing of a second layout (2'') for the module (2) of the semi-conductor memory component (1) to be used for a second configuration of the semi-conductor memory component (1);
- using of the first layout (2') or of the second lay-out (2'') for the total layout of the semi-conductor memory component (1), depending on the corresponding configuration of the semi-conductor memory component (1);
- manufacturing of a mask based on the total layout, in particular a photo mask.

17 (original). A process for manufacturing semi-conductor memory components (1) according to Claim 16, in which the process additionally comprises the step: manufacturing of a semi-conductor memory component (1) by using the manufactured mask, in particular the photo mask.